



First Named Inventor: Look, Thomas F.
No.: 57378US002
Serial No.: 10/027764
Title: Article with Retroreflective and Radio Frequency-Responsive Features

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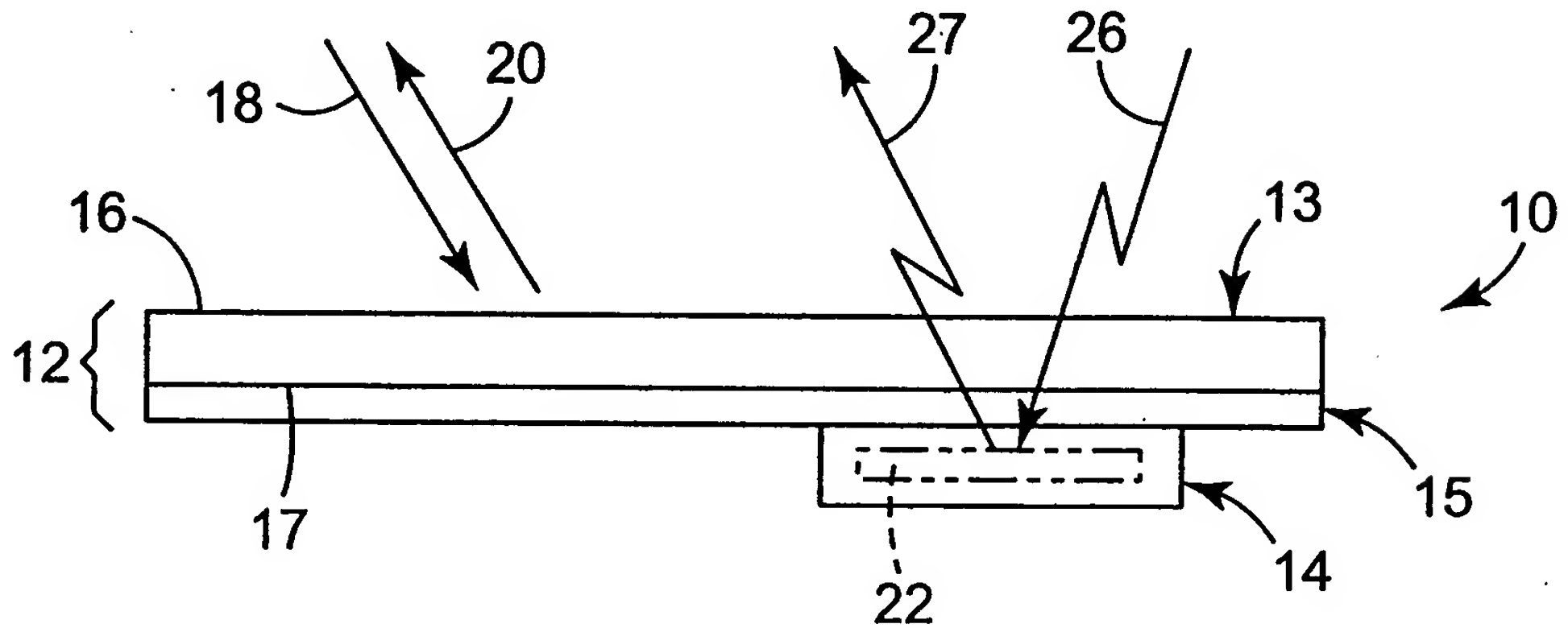


FIG. 1

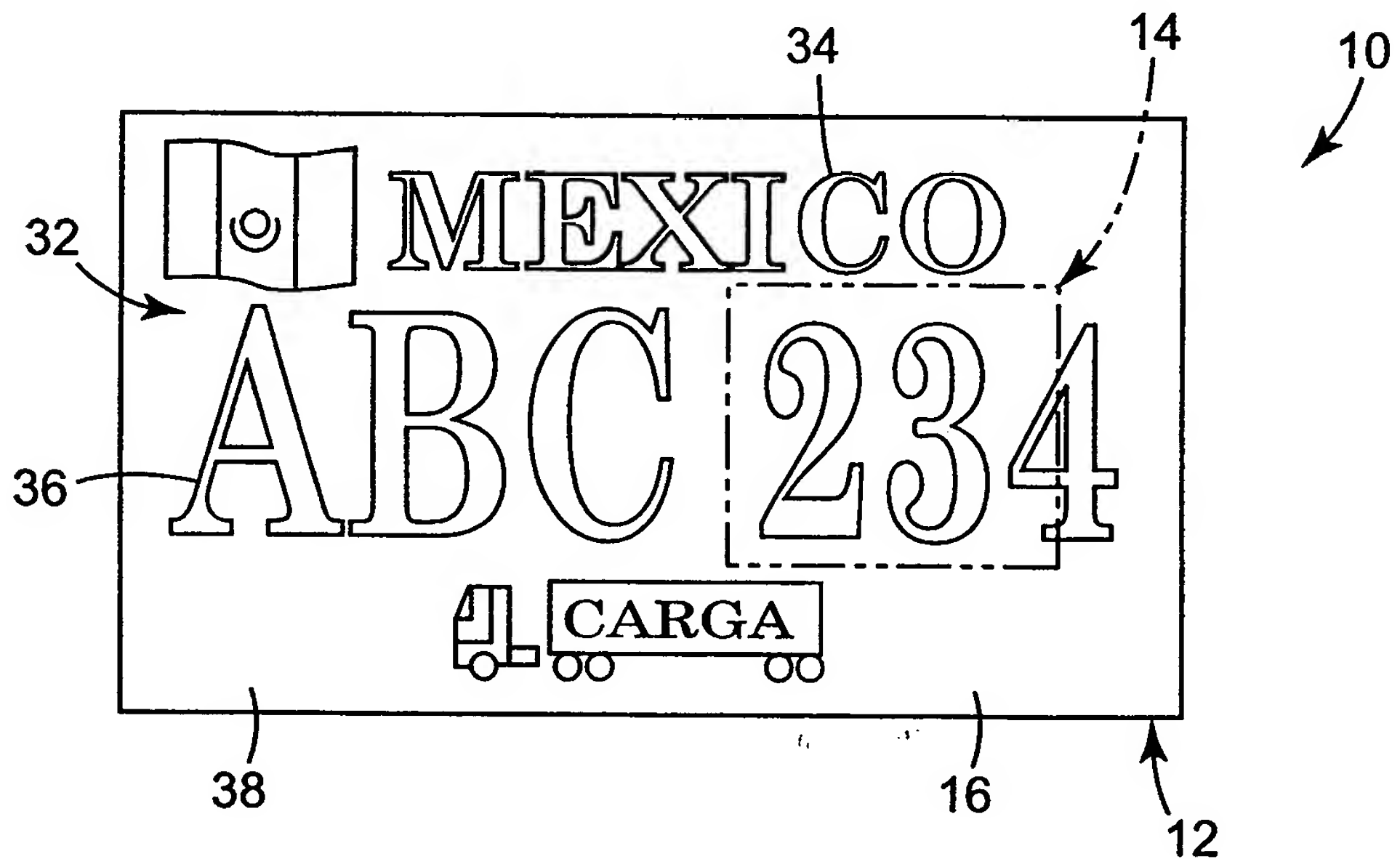


FIG. 2



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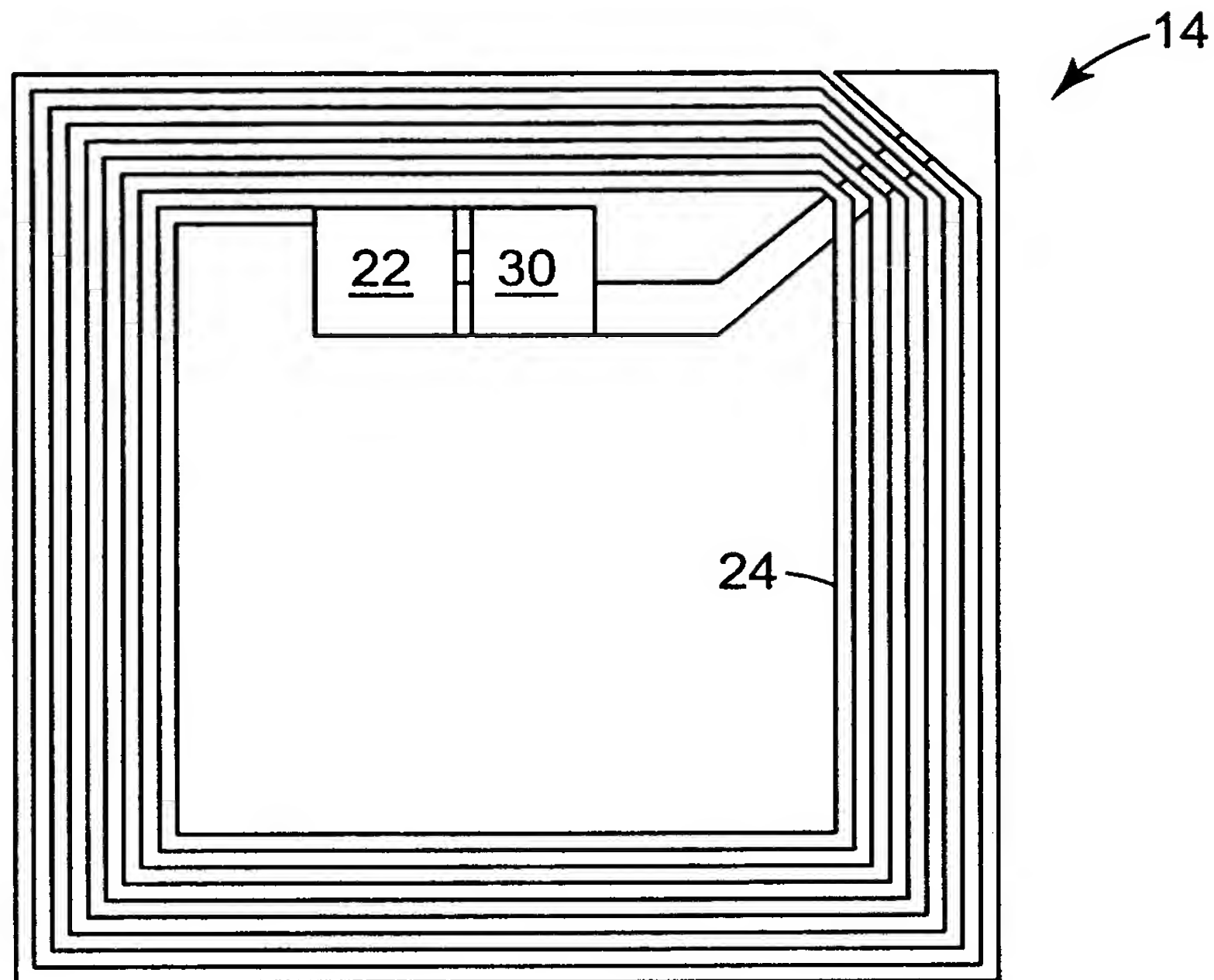


FIG. 3

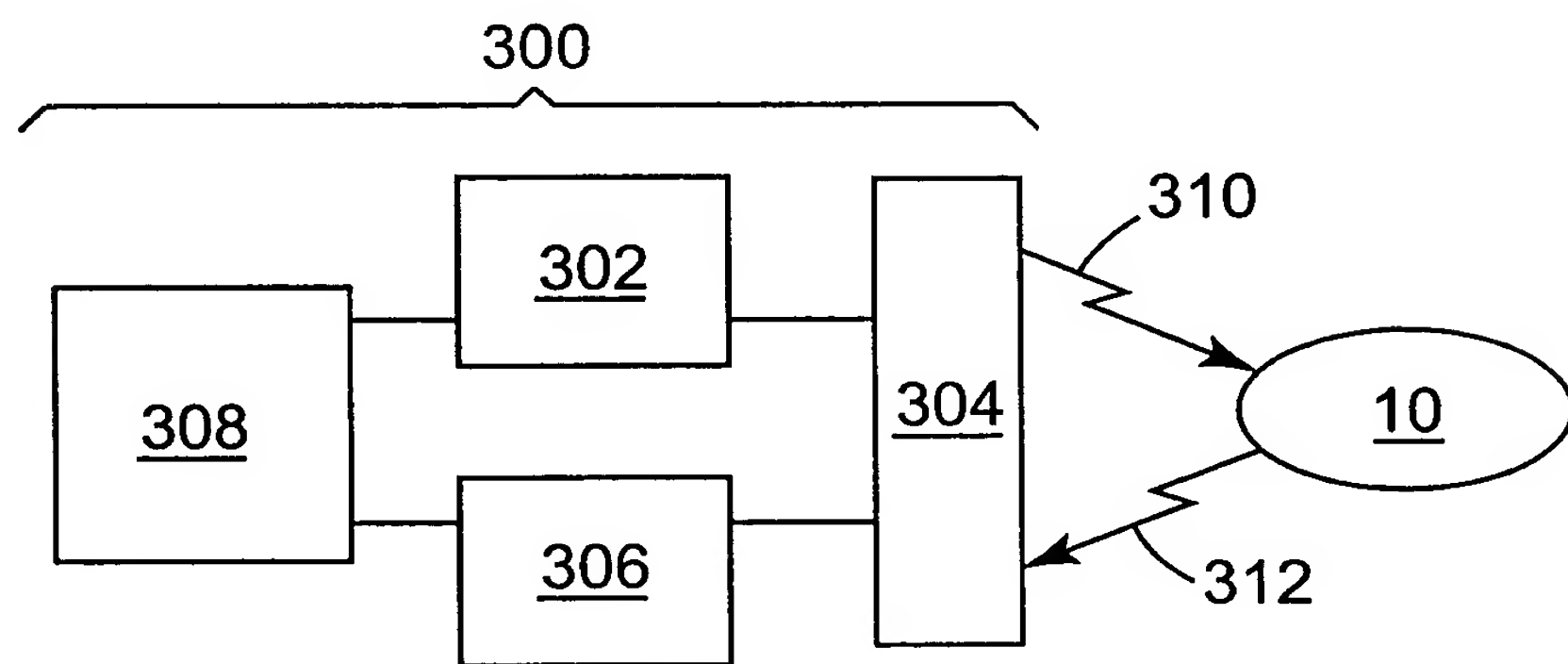
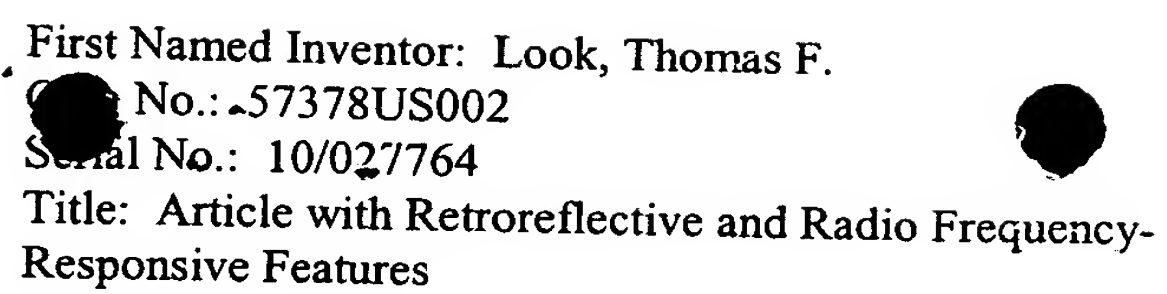


FIG. 4



A cross-sectional view of a semiconductor device 50. The device consists of a substrate 59 with a wavy interface 62. A layer 44 is on top of the substrate. A rectangular block 60 is embedded in layer 44. Above layer 44 is a layer 58 with a dotted pattern. A wavy interface 57 separates layer 58 from a layer 55 with a diagonal hatching pattern. A bracket 52 groups layers 55 and 58. A layer 54 with a diagonal hatching pattern is on top of layer 55. A layer 56 with a diagonal hatching pattern is on top of layer 54. A layer 64 with a dotted pattern is on top of layer 56. A layer 66 with a diagonal hatching pattern is on top of layer 64. A layer 68 with a dotted pattern is on top of layer 66. An arrow 53 points to the interface between layers 56 and 64. An arrow 50 points to the top surface of the device.

FIG. 6